High-side driver with current sense analog feedback for automotive applications



#### **Features**

- Operating voltage range: 4.5V to 28V
- Load current limitation
- Output short-circuit protection
- ♦ Standby current <1.0µA</p>
- On-state resistance Typ=145mΩ
- Thermal shutdown indication
- ♦ OFF-state open-load detection
- Overvoltage clamp
- Undervoltage protection
- Multiplexed analog feedback of load current with high precision proportional current mirror
- RoHS compliant and lead free

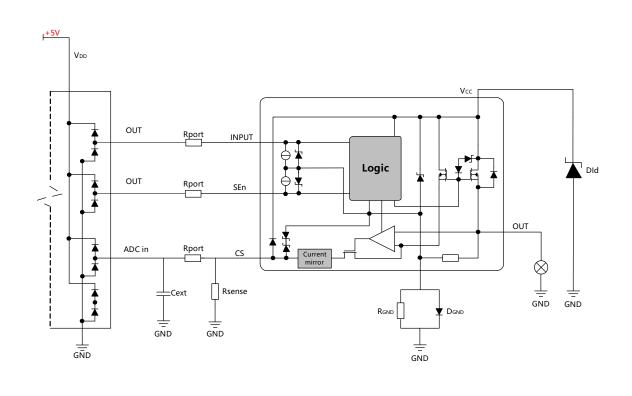
## Application

- All types of automotive resistive, inductive and capacitive loads
- Specially intended for automotive signal lamps

#### **General Description**

- WS7140S is single channel high-side drivers with current sense analog feedback for automotive applications, the devices are designed to drive 12 V automotive grounded loads through a 3 V and 5 V.
- WS7140S integrates advanced protective functions such as load current limitation, overload active management by power limitation and overtemperature shutdown.
- A dedicated multifunction multiplexed analog output pin delivers sophisticated diagnostic functions including high precision proportional load current sense, in addition to the detection of overload and short circuit to ground, short to V<sub>CC</sub> and OFF-state open-load.
- A sense enable pin allows OFF-state diagnosis to be disabled during the module low power mode as well as external sense resistor sharing among similar devices.
- WS7140S is available in ESOP-8L package.

### **Typical Application Circuit**

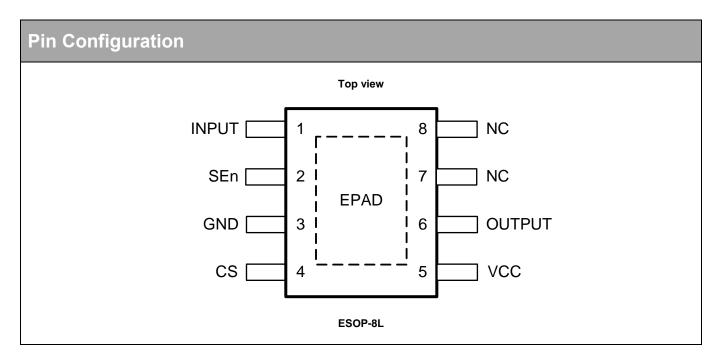


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High-side driver with current sense analog feedback for automotive applications



| Ordering Information    |          |           |
|-------------------------|----------|-----------|
| Package                 | Top Mark | Part No.  |
| 8-Pin ESOP-8L, Pb-free  | WS7140S  | WS7140S   |
| 0-FIII E30F-0L, FD-1166 | XXYMXX   | VV37 1403 |



| Pin Descr       | iption  |  |
|-----------------|---------|--|
| Pin Name        | Pin NO. | Pin Description  |
| INPUT           | 1       | Voltage controlled input pin with hysteresis, compatible with 3 V and 5 V CMOS outputs. It controls output switch state.   |
| SEn             | 2       | Active high compatible with 3 V and 5 V CMOS outputs pin, it enables the CS diagnostic pin.  |
| GND             | 3       | Ground connection. Must be reverse battery protected by an external diode / resistor network.  |
| CS              | 4       | Multiplexed analog sense output pin; it delivers a current proportional to the load current.   |
| V <sub>cc</sub> | 5       | Battery connection.  |
| OUTPUT          | 6       | Power outputs.   |
| NC              | 7/8     | No connect.  |
| EPAD            | EPAD    | Exposed pad for thermal dissipation enhancement. Must be soldered on the large ground plane on the PCB to increase the thermal dissipation. The pad must be connected to GND electrically. |

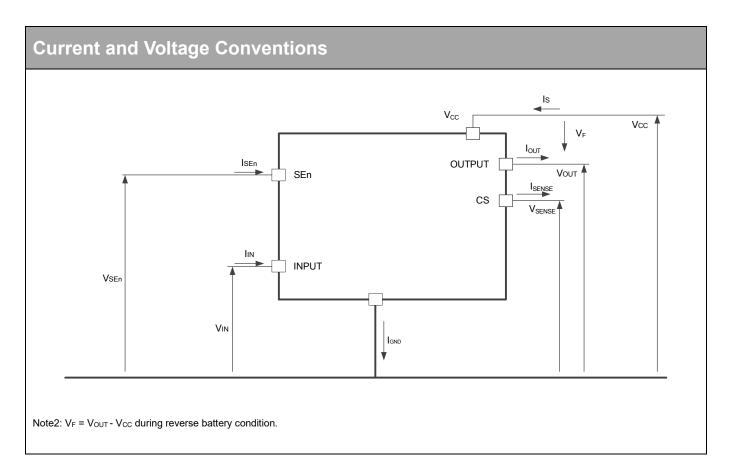
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Table 1. Suggested connections for unused and not connected pins

| Connection / pin | cs                  | OUTPUT      | INPUT                | SEn                  |
|------------------|---------------------|-------------|----------------------|----------------------|
| Floating         | Not allowed         | Х           | X                    | Х                    |
| To ground        | Through 1K resistor | Not allowed | Through 15K resistor | Through 15K resistor |

Note1: X do not care.



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| Absolute Ma                        | aximum Ratings <sup>(Note3)</sup>   |                    |       |
|------------------------------------|-------------------------------------|--------------------|-------|
| Symbol                             | Parameter                           | Value              | Unit  |
| V <sub>cc</sub>                    | DC supply voltage                   | 35                 | V     |
| -V <sub>CC</sub>                   | Reverse DC supply voltage           | 0.3                | V     |
| -I <sub>GND</sub>                  | DC reverse ground pin current       | 200                | mA    |
| I <sub>OUT</sub>                   | OUTPUT DC output current            | Internally limited | Α     |
| V <sub>IN</sub> , V <sub>SEn</sub> | INPUT, SEn DC input voltage         | -0.3 to 6.0        | V     |
|                                    | CS pin DC output current            | 20                 | 4     |
| ISENSE                             | CS pin DC output current in reverse | -20                | mA mA |
| T <sub>j</sub>                     | Junction operating temperature      | -40 to 150         | °C    |
| T <sub>stg</sub>                   | Storage temperature                 | -55 to 150         | C     |

Note3: Stressing the device above the rating listed in Absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to the conditions in table below for extended periods may affect device reliability.

| ESD Suscept                         | ibility (Note4)  |        |      |
|-------------------------------------|--|--------|------|
| Symbol                              | Parameter  | Values | Unit |
| V <sub>ESD(HBM)</sub> <sup>3)</sup> | ESD Susceptibility all Pins (HBM)                      | ±2     | kV   |
| V <sub>ESD(HBM)_</sub> OUT          | ESD Susceptibility OUT vs GND and Vcc connected (HBM)  | ±4     | kV   |
| V <sub>ESD(CDM)</sub> <sup>4)</sup> | ESD Susceptibility all Pins (CDM)                      | ±500   | V    |
| V <sub>ESD(CDM)_CRN</sub>           | ESD Susceptibility Corner Pins (CDM) (pins 1, 4, 5, 8) | ±750   | V    |

#### Note4:

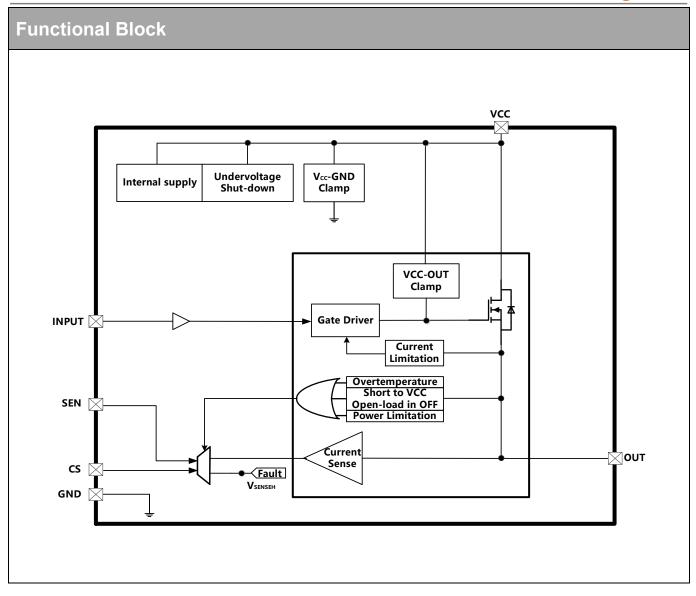
- 1) Not subject to production test specified by design.
- 2) Maximum digital input voltage to be considered for Latch-Up tests: 5.5 V.
- 3) ESD susceptibility, Human Body Model "HBM", according to AEC Q100-002.
- 4) ESD susceptibility, Charged Device Model "CDM", according to AEC Q100-011.

| Thermal Resis   | stance (Note5)                         |       |      |
|-----------------|--|-------|------|
| Symbol          | Parameter                              | Value | Unit |
| T <sub>JA</sub> | Junction-to-Ambient Thermal Resistance | 43    | °C/W |

Note5: According to JEDEC JESD51-2,-5,-7 at natural convection on FR4 2s2p board; the Product (Chip + Package) was simulated on a 76.2 × 114.3 × 1.5 mm board with 2 inner copper layers (2 × 70 µm Cu, 2 × 35 µm Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.

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## Electrical Characteristics (Note6)

| wer            | . 60 | V activities |           |
|----------------|------|--------------|-----------|
| <br>V.V.V ==11 | -1-  | 4 77 1       | ra1 II II |

| Parameter  | Symbol                 | Test Condition  | Min. | Тур. | Max. | Unit |
|--|------------------------|---|------|------|------|------|
| Operating supply voltage   | V <sub>CC</sub>        |   | 4.5  | 13   | 28   | V    |
| Under voltage shutdown   | V <sub>USD</sub>       |   |      |      | 4.5  | V    |
| Under voltage shutdown reset   | V <sub>USDReset</sub>  |   |      |      | 5    | V    |
| Under voltage shutdown hysteresis  | V <sub>USDhyst</sub>   |   |      | 0.3  |      | V    |
| On-state resistance  |                        | I <sub>OUT</sub> =1A, T <sub>j</sub> = 25°C   |      | 145  |      |      |
|  | $R_{\text{ON}}$        | I <sub>OUT</sub> =1A, T <sub>j</sub> =150°C   |      |      | 280  | mΩ   |
|  |                        | I <sub>OUT</sub> =1A, V <sub>CC</sub> =4.5V, T <sub>j</sub> = 25°C                                    |      |      | 240  |      |
| Nominal load current   | $I_{L(NOM)}$           | T <sub>A</sub> =25℃   |      | 2.0  |      | Α    |
| Nominal load current at T <sub>A</sub> =85℃  | I <sub>L(NOM)_85</sub> | T <sub>A</sub> =85℃, T <sub>j</sub> < 150℃  |      | 1.8  |      | Α    |
| Inverse Current Capability   | I <sub>L(INV)</sub>    | V <sub>CC</sub> <v<sub>OUT, V<sub>IN</sub>=5V, T<sub>A</sub>=25℃</v<sub>                              |      | 2.0  |      | Α    |
|  | .,                     | I <sub>S</sub> =20 mA, 25°C < T <sub>j</sub> < 150°C  | 35   | 42   | 48   |      |
| V <sub>CC</sub> clamp voltage  | $V_{CLAMP}$            | I <sub>S</sub> =20 mA, T <sub>j</sub> =-40°C  | 33   |      |      | V    |
| Committee and in the additional to the second secon |                        | $V_{CC} = 13V, V_{IN} = V_{OUT} = V_{SEn} = 0V, T_j = 25^{\circ}C$                                    |      |      | 1.0  | μΑ   |
| Supply current in standby at $V_{CC}$ = 13 V   | I <sub>STBY</sub>      | V <sub>CC</sub> =13V, V <sub>IN</sub> =V <sub>OUT</sub> =V <sub>SEn</sub> =0V, T <sub>j</sub> = 125°C |      |      | 3.0  | μΑ   |
| Standby mode blanking time   | t <sub>D_STBY</sub>    | $V_{CC}$ =13V, $V_{IN}$ = $V_{OUT}$ =0V, $V_{SEn}$ =5 V to 0 V  | 100  | 450  | 900  | us   |
| Supply current   | I <sub>S(ON)</sub>     | V <sub>CC</sub> =13V, V <sub>SEn</sub> =0V, V <sub>IN</sub> =5V, I <sub>OUT</sub> =0A                 |      | 3    | 6    | mA   |
| Control stage current consumption in ON state  | I <sub>GND(ON)</sub>   | V <sub>CC</sub> =13V, V <sub>SEn</sub> =5V, V <sub>IN</sub> =5V, I <sub>OUT</sub> =1A                 |      |      | 6    | mA   |
| 0# -1-1  |                        | $V_{IN} = V_{OUT} = 0V$ , $V_{CC} = 13V$ , $T_j = 25^{\circ}C$  | 0    | 0.05 | 0.5  | μΑ   |
| Off-state output current at V <sub>CC</sub> =13V   | $I_{L(off)}$           | V <sub>IN</sub> =V <sub>OUT</sub> =0V, V <sub>CC</sub> =13V, T <sub>j</sub> =125°C                    | 0    |      | 3.0  | μA   |
| Output - V <sub>CC</sub> diode voltage at T <sub>j</sub> =150°C  | V <sub>F</sub>         | I <sub>OUT</sub> =-0.2A, T <sub>j</sub> =150°C  |      |      | 0.9  | V    |

#### Switching/V<sub>CC</sub> = 13 V, -40°C < $T_j$ < 150°C, unless otherwise specified

| Parameter   | Symbol                                 | Test Condition      | Min. | Тур. | Max. | Unit |
|---|--|---------------------|------|------|------|------|
| Turn-on delay time at T <sub>j</sub> = 25°C                   | T <sub>d (on)</sub>                    | D =120              | 10   | 35   | 120  | us   |
| Turn-off delay time at T <sub>j</sub> = 25°C                  | T <sub>d (off)</sub>                   | R <sub>L</sub> =13Ω | 10   | 60   | 120  | us   |
| Turn-on voltage slope at T <sub>j</sub> = 25°C                | (dV <sub>OUT</sub> /dt) <sub>on</sub>  | D -420              | 0.05 | 0.2  | 0.7  | V/us |
| Turn-off voltage slope at T <sub>j</sub> = 25°C               | (dV <sub>OUT</sub> /dt) <sub>off</sub> | R <sub>L</sub> =13Ω | 0.05 | 0.45 | 0.7  | v/us |
| Differential pulse skew(t <sub>PHL</sub> - t <sub>PLH</sub> ) | t <sub>skew</sub>                      | $R_L$ =13 $\Omega$  | -60  | -10  | 60   | us   |

#### Logic input (IN, SEn)

| Parameter                      | Symbol              | Test Condition         | Min. | Тур. | Max. | Unit |
|--------------------------------|---------------------|------------------------|------|------|------|------|
| Logic input low level voltage  | V <sub>L</sub>      |                        |      |      | 0.9  | ٧    |
| Low level logic input current  | Iμ                  | V <sub>INL</sub> =0.9V | 0.5  |      |      | uA   |
| Logic input high level voltage | V <sub>H</sub>      |                        | 2.1  |      | 6.0  | ٧    |
| High level logic input current | I <sub>H</sub>      | V <sub>INH</sub> =2.1V |      |      | 12   | uA   |
| Logic input hysteresis voltage | V <sub>(hyst)</sub> |                        | 0.1  | 0.3  | 0.7  | V    |

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| Protections (7 V < V <sub>CC</sub> < 18 V, -40             |                           |   | I                   | I                   |                     |            |
|--|---------------------------|---|---------------------|---------------------|---------------------|------------|
| Parameter  | Symbol                    | Test Condition  | Min.                | Тур.                | Max.                | Unit       |
| DC short circuit current                                   | I <sub>LIMH</sub>         | V <sub>CC</sub> =13V  | 4                   | 6                   | 10                  |            |
| DO SHORE SUPERIOR  | LIMH                      | 4.5V < V <sub>CC</sub> < 16V  |                     |                     | 10                  | Α          |
| Short circuit current during thermal cycling               | I <sub>LIML</sub>         | $V_{CC}$ =13 $V$ , $T_R$ < $T_j$ < $T_{TSD}$  |                     | 2                   |                     |            |
| Shutdown temperature                                       | $T_{TSD}$                 |   | 150                 | 175                 | 200                 | °C         |
| Thermal hysteresis   | $T_{HYST}$                |   |                     | 20                  |                     | °C         |
| Dynamic temperature  | $\Delta T_{\text{J\_SD}}$ | $T_j = -40$ °C, $V_{CC}=13V$  |                     | 60                  |                     | °C         |
| Current limit thermal hysteresis                           | T <sub>R</sub>            |   |                     | 40                  |                     | $^{\circ}$ |
| Turn-off output voltage clamp                              |                           | $I_{OUT}$ =1A, L= 6mH, $T_j$ = -40°C  | V <sub>cc</sub> -33 |                     |                     | .,         |
|  | $V_{DEMAG}$               | I <sub>OUT</sub> =1A, L= 6mH, T <sub>j</sub> =25°C to 150°C   | V <sub>cc</sub> -35 | V <sub>CC</sub> -38 | V <sub>CC</sub> -43 | V          |
| Current sense / 7 V < V <sub>CC</sub> < 18 V,              | -40°C < T <sub>j</sub> <  | < 150℃  |                     |                     |                     |            |
| Parameter  | Symbol                    | Test Condition  | Min.                | Тур.                | Max.                | Unit       |
|  | .,                        | V <sub>SEn</sub> =0V, I <sub>SENSE</sub> =1mA   |                     | -15                 |                     |            |
| Current sense clamp voltage                                | V <sub>SENSE_CL</sub>     | V <sub>SEn</sub> =0V, I <sub>SENSE</sub> = -1mA   |                     | 7                   |                     | V          |
| Current sense characteristics                              |                           |   |                     |                     |                     |            |
| Parameter  | Symbol                    | Test Condition  | Min.                | Тур.                | Max.                | Unit       |
| I <sub>OUT</sub> /I <sub>SENSE</sub>                       | K <sub>1</sub>            | I <sub>OUT</sub> =0.15A, V <sub>SEn</sub> =5V   | -50%                | 530                 | +50%                |            |
| I <sub>OUT</sub> /I <sub>SENSE</sub>                       | K <sub>2</sub>            | I <sub>OUT</sub> =0.7A, V <sub>SEn</sub> =5V  | -15%                | 520                 | +15%                |            |
| I <sub>OUT</sub> /I <sub>SENSE</sub>                       | K <sub>3</sub>            | I <sub>OUT</sub> =1A, V <sub>SEn</sub> =5V  | -10%                | 520                 | +10%                |            |
| I <sub>OUT</sub> /I <sub>SENSE</sub>                       | $K_4$                     | I <sub>OUT</sub> =2A, V <sub>SEn</sub> =5V  | -8%                 | 520                 | +8%                 |            |
|  |                           | CS disabled: V <sub>SEn</sub> =0V   | 0                   |                     | 0.5                 |            |
| Comment conce legicare somest                              | ,                         | CS disabled: -1V <v<sub>SENSE&lt;5V</v<sub>   | -0.5                |                     | 3                   | - uA       |
| Current sense leakage current                              | I <sub>SENSE0</sub>       | CS enabled: V <sub>SEn</sub> =5V, V <sub>IN</sub> = 5V, I <sub>OUT</sub> =0A                        | 0                   |                     | 100                 |            |
|  |                           | CS enabled: V <sub>SEn</sub> =5V, V <sub>IN</sub> = 0V, I <sub>OUT</sub> =0A                        | 0                   |                     | 2                   |            |
| Output voltage for CS shutdown                             | V <sub>OUT_MSD</sub>      | V <sub>SEn</sub> =5V, R <sub>SENSE</sub> =2.7K, V <sub>IN</sub> =5V, I <sub>OUT</sub> =1A           |                     | 5                   |                     | V          |
| CS saturation voltage                                      | V <sub>SENSE SAT</sub>    | V <sub>CC</sub> =7V,R <sub>SENSE</sub> =2.7K,V <sub>SEn</sub> =5V,V <sub>IN</sub> =5V,              | 5                   |                     |                     | V          |
| OG Saturation Voltage                                      | V SENSE_SAT               | I <sub>OUT</sub> =2A, T <sub>j</sub> =150 °C  | 3                   |                     |                     |            |
| CS saturation current                                      | I <sub>SENSE_SAT</sub>    | V <sub>CC</sub> =7V, V <sub>SENSE</sub> =4V, V <sub>IN</sub> =5V, V <sub>SEn</sub> =5V,             | 4                   |                     |                     | mA         |
|  |                           | T <sub>j</sub> =150°C   |                     |                     |                     |            |
| Output saturation current                                  | I <sub>OUT_SAT</sub>      | $V_{CC}=7V$ , $V_{SENSE}=4V$ , $V_{IN}=5V$ , $V_{SEn}=5V$ , $V_{j}=150$ °C                          | 2.2                 |                     |                     | Α          |
| OFF-state diagnostic                                       |                           |   | l<br>               |                     |                     |            |
| Parameter  | Symbol                    | Test Condition  | Min.                | Тур.                | Max.                | Unit       |
| OFF-state open load voltage detection                      |                           | V 5V V 5V   | _                   | _                   |                     |            |
| threshold  | V <sub>OL</sub>           | V <sub>SEn</sub> =5V, V <sub>IN</sub> =0V   | 2                   | 3                   | 4                   | V          |
| OFF-state output sink current                              | I <sub>L(off2)</sub>      | $V_{IN} = 0 \text{ V}, V_{OUT} = V_{OL}, T_j = -40^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}$ | -450                | -200                | -80                 | uA         |
| OFF-state diagnostic delay time from falling edge of INPUT | t <sub>DSTKON</sub>       | V <sub>SEn</sub> =5V, V <sub>IN</sub> = 5V to 0 V, V <sub>OUT</sub> =4V,<br>I <sub>OUT</sub> =0A    | 100                 | 350                 | 700                 | us         |

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# WS7140S Product Description High-side driver with current sense analog feedback for automotive applications



| Settling time for valid OFF-state open load diagnostic indication from rising edge of SEn   | $t_{	extsf{D}_{-}	extsf{OL}_{-}	extsf{V}}$ | $V_{IN}$ =0V, $V_{OUT}$ =4V, $V_{SEn}$ = 0V to 5V  |      |               | 150            | us                |  |  |
|---|--|--|------|---------------|----------------|-------------------|--|--|
| OFF-state diagnostic delay time from rising edge of V <sub>OUT</sub>  | t <sub>D_VOL</sub>                         | V <sub>SEn</sub> =5V,V <sub>IN</sub> =0V, V <sub>OUT</sub> =0V to 4V   |      | 5             | 30             | us                |  |  |
| Fault diagnostic feedback   | Fault diagnostic feedback                  |  |      |               |                |                   |  |  |
| Parameter   | Symbol                                     | Test Condition   | Min. | Тур.          | Max.           | Unit              |  |  |
| Current sense output voltage in fault condition   | V <sub>SENSEH</sub>                        | $V_{CC}$ =13V, $R_{SENSE}$ =1K, $V_{IN}$ =0V, $V_{SEn}$ = 5V, $I_{OUT}$ =0A, $V_{OUT}$ =4V   | 5.0  | 6.0           | 6.6            | V                 |  |  |
| Current sense output current in fault condition   | Isenseh                                    | V <sub>CC</sub> =13V, V <sub>SENSE</sub> =5V   | 10   | 20            | 30             | mA                |  |  |
| Current sense timings   |  |  |      |               |                |                   |  |  |
|   |  |  |      |               |                |                   |  |  |
| Parameter   | Symbol                                     | Test Condition   | Min. | Тур.          | Max.           | Unit              |  |  |
| Parameter  Current sense settling time from rising edge of SEn  | Symbol t <sub>DSENSE1H</sub>               | Test Condition $V_{\text{IN}}=5\text{V, }V_{\text{Sen}}=0\text{V to }5\text{V,}$ $R_{\text{SENSE}}=1\text{K, }R_{\text{L}}=13\Omega$   | Min. | Тур.          | <b>Max.</b> 60 | <b>Unit</b><br>us |  |  |
| Current sense settling time from rising   |  | V <sub>IN</sub> =5V, V <sub>SEn</sub> =0V to 5V,   | Min. | <b>Typ.</b> 5 |                |                   |  |  |
| Current sense settling time from rising edge of SEn  Current sense disable delay time from  | t <sub>DSENSE1H</sub>                      | $V_{IN}$ =5V, $V_{SEn}$ =0V to 5V, $R_{SENSE}$ =1K, $R_L$ =13 $\Omega$ $V_{IN}$ =5V, $V_{SEn}$ =5V to 0V,  | Min. | ,,            | 60             | us                |  |  |
| Current sense settling time from rising edge of SEn  Current sense disable delay time from falling edge of SEn  Current sense settling time from rising | t <sub>DSENSE1H</sub>                      | $V_{\text{IN}} = 5\text{V}, \ V_{\text{SEn}} = 0\text{V to }5\text{V},$ $R_{\text{SENSE}} = 1\text{K}, \ R_{\text{L}} = 13\Omega$ $V_{\text{IN}} = 5\text{V}, \ V_{\text{SEn}} = 5\text{V to }0\text{V},$ $R_{\text{SENSE}} = 1\text{K}, \ R_{\text{L}} = 13\Omega$ $V_{\text{IN}} = 0\text{V to }5\text{V}, \ V_{\text{SEn}} = 5\text{ V},$ | Min. | 5             | 60             | us                |  |  |

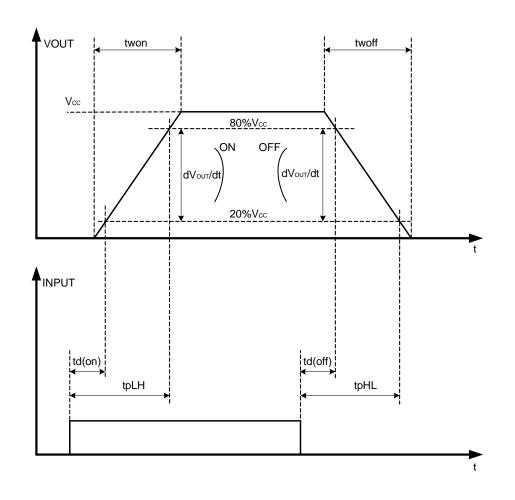
Note6: Except for the special test instructions, all electrical parameters are tested under TA= +25°C. The minimum and maximum specification range of the specifications is guaranteed by the test, and the typical values are guaranteed by the design, test, or statistical analysis.

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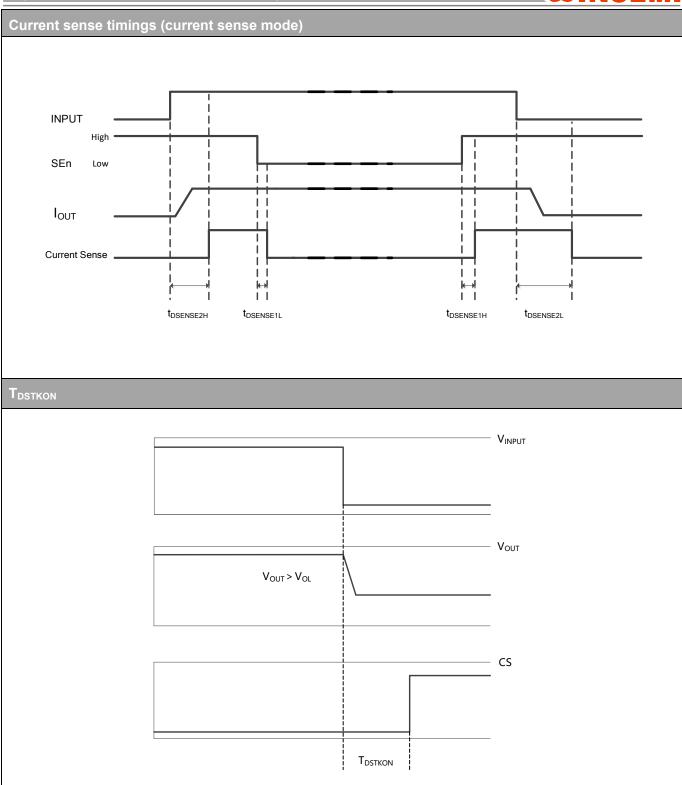
## **Switching Status and Timing Relationship**

Switching time and pulse skew



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#### Table 2. Truth table

| Mode                    | Conditions   | IN | SEn         | OUT | Current sense | Comments   |  |  |  |
|-------------------------|--|----|-------------|-----|---------------|--|--|--|--|
| Standby                 | All logic INs low  | L  | L           | L   | Hi-Z          | Low quiescent current consumption                                |  |  |  |
| Normal                  | Nominal load connected;  | L  | See Table 3 | L   | See Table 3   |  |  |  |  |
|                         | T <sub>j</sub> < 150℃  | Н  | See Table 3 | Н   | See Table 3   |  |  |  |  |
| Overload                | Overload or short to GND   | L  |             | L   | See Table 3   |  |  |  |  |
|                         | causing: $T_{j} > T_{TSD} \text{ or }$ $\Delta T_{j} > \Delta T_{j\_SD}$ | Н  | See Table 3 | Н   | See Table 3   | Output cycles with temperature hysteresis                        |  |  |  |
| Undervoltage            | V <sub>CC</sub> <v<sub>USD</v<sub>                                       | Х  | X           | L   | Hi-Z          | Re-start when $V_{CC} > V_{USD} + V_{USDhyst} \text{ (rising )}$ |  |  |  |
| OFF-state diagnostics   | Short to V <sub>CC</sub>   | L  | Can Table 2 | Н   | See Table 3   |  |  |  |  |
|                         | Open-Load  | L  | See Table 3 | Н   | See Table 3   | External pull-up   |  |  |  |
| Negative output voltage | Inductive loads turn-off   | L  | See Table 3 | <0  | See Table 3   |  |  |  |  |

#### Table 3. Current sense output

| SEn | MUX Channel        | Current sense output    |                          |  |                 |  |
|-----|--------------------|-------------------------|--------------------------|--|-----------------|--|
|     |                    | Normal                  | Overload                 | OFF-state                                | Negative output |  |
| L   |                    | Hi-Z                    |                          |  |                 |  |
| Н   | Channel diagnostic | $I_{SENSE} = I_{OUT}/K$ | $V_{SENSE} = V_{SENSEH}$ | V <sub>SENSE</sub> = V <sub>SENSEH</sub> | Hi-Z            |  |

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High-side driver with current sense analog feedback for automotive applications



### **Functional Description**

#### **Power limitation**

The basic working principle of this protection consists of an indirect measurement of the junction temperature swing  $\Delta T_j$  through the direct measurement of the spatial temperature gradient on the device surface in order to automatically shut off the output MOSFET as soon as  $\Delta T_j$  exceeds the safety level of  $\Delta T_{j\_SD}$ . The protection prevents fast thermal transient effects and, consequently, reduces thermo-mechanical fatigue.

#### Thermal shutdown

In case the junction temperature of the device exceeds the maximum allowed threshold (typically 175°C), it automatically switches off and the diagnostic indication is triggered.

#### **Current limitation**

The device is equipped with an output current limiter in order to protect the silicon as well as the other components of the system (e.g. bonding wires, wiring harness, connectors, loads, etc.) from excessive current flow. Consequently, in case of short circuit, overload or during load power-up, the output current is clamped to a safety level, ILIMH, by operating the output power MOSFET in the active region.

#### **Negative voltage clamp**

In case the device drives inductive load, the output voltage reaches a negative value during turn off. A negative voltage clamp structure limits the maximum negative voltage to a certain value, V<sub>DEMAG</sub>, allowing the inductor energy to be dissipated without damaging the device.

#### Diode (D<sub>GND</sub>) in the ground line

A resistor (typ.R<sub>GND</sub>=4.7K) should be inserted in parallel to D<sub>GND</sub> if the device drives an inductive load. This small signal diode can be safely shared amongst several different HSDs. Also in this case, the presence of the ground network produces a shift ( $\approx$ 600mV) in the input threshold and in the status output values if the microprocessor ground is not common to the device ground. This shift does not vary if more than one HSD shares the same diode/resistor network.

#### **MCU I/Os protection**

If a ground protection network is used and negative transients are present on the  $V_{CC}$  line, the control pins will be pulled negative. WS suggests to insert a resistor ( $R_{prot}$ =15K) in line both to prevent the micro-controller I/O pins from latching-up and to protect the HSD inputs. The value of these resistors is a compromise between the leakage current of micro-controller and the current required by the HSD I/Os (Input levels compatibility) with the latch-up limit of micro-controller I/Os.

#### CS - analog current sense

Diagnostic information on device and load status are provided by an analog output pin (CS) delivering the current mirror of channel output current. The signal are routed through an analog multiplexer which is controlled by mean of SEn pin, according to the address map in CS multiplexer addressing Table.

#### **Current monitor**

When current mode is selected in the CS, this output is capable to provide:

- Current mirror proportional to the load current in normal operation, delivering current proportional to the load according to known ratio named K
- Diagnostics flag in fault conditions delivering fixed voltage V<sub>SENSEH</sub>

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#### WS7140S Product Description

## High-side driver with current sense analog feedback for automotive applications



The current delivered by the current sense circuit, I<sub>SENSE</sub> can be easily converted to a voltage V<sub>SENSE</sub> by using an external sense resistor, R<sub>SENSE</sub>, allowing continuous load monitoring and abnormal condition detection.

While device is operating in normal conditions (no fault intervention), V<sub>SENSE</sub> calculation can be done using simple equations.

Current provided by CS output: ISENSE = IOUT/K

Voltage on R<sub>SENSE</sub>: V<sub>SENSE</sub> = R<sub>SENSE</sub>\*I<sub>SENSE</sub> = R<sub>SENSE</sub>\* I<sub>OUT</sub>/K

Where:

Vsense is voltage measurable on Rsense resistor

 $I_{\text{SENSE}}$  is current provided from CS pin in current output mode

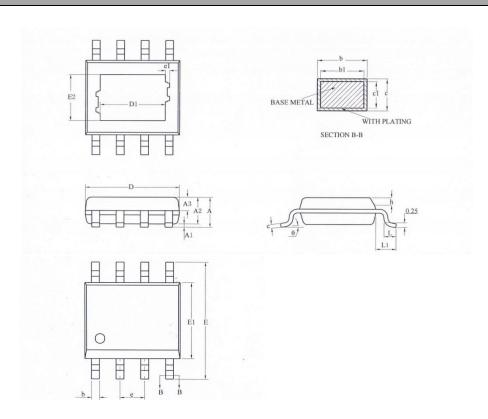
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## Package Outline

## ESOP-8L



| 0)/44001 | MILLIMETER |      |      |  |  |
|----------|------------|------|------|--|--|
| SYMBOL   | MIN        | NOM  | MAX  |  |  |
| Α        |            |      | 1.65 |  |  |
| A1       | 0.05       |      | 0.15 |  |  |
| A2       | 1.30       | 1.40 | 1.50 |  |  |
| А3       | 0.60       | 0.65 | 0.70 |  |  |
| b        | 0.39       |      | 0.47 |  |  |
| b1       | 0.38       | 0.41 | 0.44 |  |  |
| С        | 0.20       |      | 0.24 |  |  |
| c1       | 0.19       | 0.20 | 0.21 |  |  |
| D        | 4.80       | 4.90 | 5.00 |  |  |
| D1       | 3.10REF    |      |      |  |  |
| E        | 5.80       | 6.00 | 6.20 |  |  |
| E1       | 3.80       | 3.90 | 4.00 |  |  |
| E2       | 2.21REF    |      |      |  |  |
| е        | 1.27BSC    |      |      |  |  |
| h        | 0.25       |      | 0.50 |  |  |
| L        | 0.50       | 0.60 | 0.80 |  |  |
| L1       | 1.05REF    |      |      |  |  |
| θ        | 0          |      | 8°   |  |  |

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#### WS7140S Product Description

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